

3KASMC10 thru 3KASMC43A

Vishay General Semiconductor

Surface Mount PAR[®] Transient Voltage Suppressors

High Temperature Stability and High Reliability Conditions



DO-214AB (SMC)

PRIMARY CHARACTERISTICS					
V _{WM}	10 V to 43 V				
V _{BR}	11.1 V to 52.8 V				
P _{PPM}	3000 W				
PD	6.0 W				
I _{FSM}	200 A				
T _J max.	185 °C				
Polarity	Uni-directional				
Package	DO-214AB (SMC)				

FEATURES

- Junction passivation optimized design passivated anisotropic rectifier technology
- T_J = 185 °C capability suitable for high reliability and automotive requirement
- Available in uni-directional polarity only
- 3000 W peak pulse power capability with a 10/1000 µs waveform
- Excellent clamping capability
- Very fast response time
- Low incremental surge resistance
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 $^{\circ}\mathrm{C}$
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

Use in sensitive electronics protection against voltage transients induced by inductive load switching and lighting on ICs, MOSFET, signal lines of sensor units for consumer, computer, industrial, automotive, and telecommunication.

MECHANICAL DATA

Case: DO-214AB (SMC)

Molding compound meets UL 94 V-0 flammability rating Base P/NHE3_X - RoHS-compliant and AEC-Q101 qualified ("X" denotes revision code e.g. A, B, ..., revision code only applicable for part number with \pm 5 % tolerance)

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

HE3 suffix meets JESD 201 class 2 whisker test

Polarity: color band denotes cathode end

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL	VALUE	UNIT			
Peak pulse power dissipation with a 10/1000 μs waveform $^{(1)}$ (fig. 3)	P _{PPM}	3000	W			
Peak power pulse current with a 10/1000 μ s waveform ⁽¹⁾ (fig. 1)	I _{PPM}	See next table	А			
Peak forward surge current 8.3 ms single half sine-wave ⁽²⁾	I _{FSM}	200	А			
Power dissipation on infinite heatsink, $T_L = 75 \text{ °C}$ (fig. 6)	PD	6.0	W			
Maximum instantaneous forward voltage at 100 A ⁽²⁾	V _F	3.5	V			
Operating junction and storage temperature range	T _J , T _{STG}	-65 to +185	°C			

Notes

 $^{(1)}$ Non-repetitive current pulse, per fig. 3 and derated above T_A = 25 °C per fig. 2.

⁽²⁾ Measured on 8.3 ms single half sine-wave, or equivalent square wave, duty cycle = 4 pulses per minute maximum

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ELECTRICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$ unless otherwise noted)									
DEVICE TYPE	DEVICE MARKING CODE	BREAKDOWN VOLTAGE V _{BR} AT I _T ⁽¹⁾ (V)		TEST CURRENT I _T (mA)	STAND-OFF VOLTAGE V _{WM} (V)	MAXIMUM REVERSE LEAKAGE AT V _{WM}	MAXIMUM REVERSE LEAKAGE AT V _{WM} Ι _D (μΑ)	MAXIMUM PEAK PULSE SURGE CURRENT	MAXIMUM CLAMPING VOLTAGEAT I _{PPM}
		MIN.	MAX.	. ,	.,	Ι _R (μΑ)	T _J = 150 °C	I _{PPM} (A) ⁽²⁾	V _C (V)
3KASMC10	3AW	11.1	13.6	1.0	10	5.0	50	160	18.8
3KASMC10A	3AX	11.1	12.3	1.0	10	5.0	50	177	17.0
3KASMC11	3AY	12.2	14.9	1.0	11	5.0	50	149	20.1
3KASMC11A	3AZ	12.2	13.5	1.0	11	5.0	50	165	18.2
3KASMC12	3BD	13.3	16.3	1.0	12	2.0	20	136	22.0
3KASMC12A	3BE	13.3	14.7	1.0	12	2.0	20	151	19.9
3KASMC13	3BF	14.4	17.6	1.0	13	2.0	20	126	23.8
3KASMC13A	3BG	14.4	15.9	1.0	13	2.0	20	140	21.5
3KASMC14	3BH	15.6	19.1	1.0	14	1.0	10	116	25.8
3KASMC14A	3BK	15.6	17.2	1.0	14	1.0	10	129	23.2
3KASMC15	3BL	16.7	20.4	1.0	15	1.0	10	112	26.9
3KASMC15A	3BM	16.7	18.5	1.0	15	1.0	10	123	24.4
3KASMC16	3BN	17.8	21.8	1.0	16	1.0	10	104	28.8
3KASMC16A	3BP	17.8	19.7	1.0	16	1.0	10	115	26.0
3KASMC17	3BQ	18.9	23.1	1.0	17	1.0	10	98.4	30.5
3KASMC17A	3BR	18.9	20.9	1.0	17	1.0	10	109	27.6
3KASMC18	3BS	20.0	24.4	1.0	18	1.0	10	93.2	32.2
3KASMC18A	3BT	20.0	22.1	1.0	18	1.0	10	103	29.2
3KASMC20	3BU	22.2	27.1	1.0	20	1.0	10	83.8	35.8
3KASMC20A	3BV	22.2	24.5	1.0	20	1.0	10	92.6	32.4
3KASMC22	3BW	24.4	29.8	1.0	22	1.0	10	76.1	39.4
3KASMC22A	3BX	24.4	26.9	1.0	22	1.0	10	84.5	35.5
3KASMC24	3BY	26.7	32.6	1.0	24	1.0	10	69.8	43.0
3KASMC24A	3BZ	26.7	29.5	1.0	24	1.0	10	77.1	38.9
3KASMC26	3CD	28.9	35.3	1.0	26	1.0	10	64.4	46.6
3KASMC26A	3CE	28.9	31.9	1.0	26	1.0	10	71.3	42.1
3KASMC28	3CF	31.1	38.0	1.0	28	1.0	10	60.0	50.0
3KASMC28A	3CG	31.1	34.4	1.0	28	1.0	10	66.1	45.4
3KASMC30	3CH	33.3	40.7	1.0	30	1.0	15	56.1	53.5
3KASMC30A	3CK	33.3	36.8	1.0	30	1.0	15	62.0	48.4
3KASMC33	3CL	36.7	44.9	1.0	33	1.0	15	50.8	59.0
3KASMC33A	3CM	36.7	40.6	1.0	33	1.0	15	56.3	53.3
3KASMC36	3CN	40.0	48.9	1.0	36	1.0	20	46.7	64.3
3KASMC36A	3CP	40.0	44.2	1.0	36	1.0	20	51.6	58.1
3KASMC40	3CQ	44.4	54.3	1.0	40	1.0	20	42.0	71.4
3KASMC40A	3CR	44.4	49.1	1.0	40	1.0	20	46.5	64.5
3KASMC43	3CS	47.8	58.4	1.0	43	1.0	20	39.1	76.7
3KASMC43A	3CT	47.8	52.8	1.0	43	1.0	20	43.2	69.4

Notes

⁽¹⁾ Pulse test: $t_p \le 50 \text{ ms}$

⁽²⁾ Surge current waveform per fig. 3 and derate per fig. 2

(3) All terms and symbols are consistent with ANSI/IEEE C62.35

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THERMAL CHARACTERISTICS ($T_A = 25 \text{ °C}$ unless otherwise noted)						
PARAMETER	SYMBOL	VALUE	UNIT			
Typical thermal resistance, junction to ambient air ⁽¹⁾	$R_{ heta JA}$	77.5	°C/W			
Typical thermal resistance, junction to leads	$R_{ ext{ heta}JL}$	18.3	0/ 10			

Note

⁽¹⁾ Mounted on minimum recommended pad layout

ORDERING INFORMATION (Example)						
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
3KASMC10AHE3_A/H ⁽¹⁾	0.211	Н	850	7" diameter plastic tape and reel		
3KASMC10AHE3_A/I (1)	0.211	I	3500	13" diameter plastic tape and reel		
3KASMC10AHE3_B/H ⁽¹⁾	0.211	н	850	7" diameter plastic tape and reel		
3KASMC10AHE3_B/I (1)	0.211	I	3500	13" diameter plastic tape and reel		

Note

(1) AEC-Q101 qualified

RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

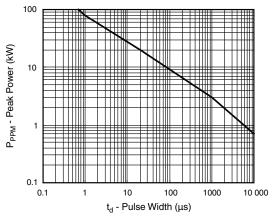


Fig. 1 - Peak Pulse Power Rating Curve

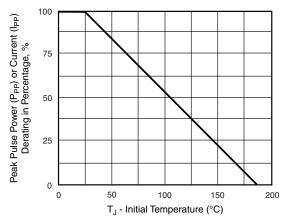


Fig. 2 - Pulse Power or Current vs. Initial Junction Temperature

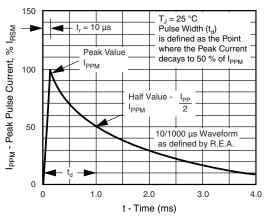


Fig. 3 - Pulse Waveform

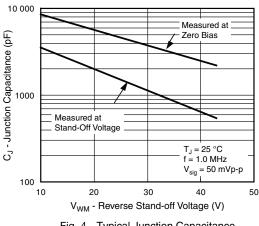


Fig. 4 - Typical Junction Capacitance

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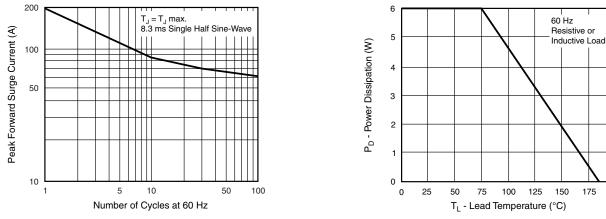
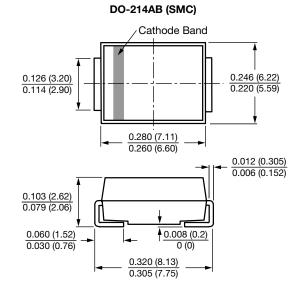


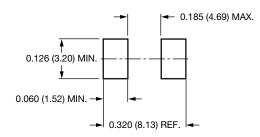
Fig. 5 - Maximum Non-Repetitive/Peak Forward Surge Current





Mounting Pad Layout

Fig. 6 - Power Derating Curve





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